

¹⁶²Os α decay (2.1 ms) [1996Bi07](#),[2000Ma95](#),[1989Ho12](#)

Type	Author	History	Literature Cutoff Date
		Citation	
Full Evaluation	N. Nica	ENSDF	31-Dec-2017

Parent: ¹⁶²Os: E=0.0; J π =0⁺; T_{1/2}=2.1 ms I; Q(α)=6767 3; % α decay=100.0

¹⁶²Os-T_{1/2}: From ¹⁶²Os Adopted Levels, Gammas dataset ([2007Re16](#)), weighted average of 1.9 ms 2 ([2000Ma95](#), α (t)) and 2.1 ms I ([2004Jo12](#), α (t)). Others: 1.5 ms +7-5, ([1996Bi07](#), α (t)); and 1.9 ms 7, ([1989Ho12](#), α (t)).

¹⁶²Os-Q(α): From [2017Wa10](#).

[1989Ho12](#): produced by ¹⁰⁶Cd(⁵⁸Ni,2n).

[1996Bi07](#): produced by ⁹²Mo(⁷⁸Kr,x) at 357 and 384 MeV and products separated in fragment mass analyzer and counted in silicon strip detector.

[2000Ma95](#): produced by ¹⁰⁶Cd(⁵⁸Ni,x) at 270 MeV and products separated in fragment mass analyzer and counted in silicon strip detector.

¹⁵⁸W Levels

E(level)	J π	Comments
0.0	0 ⁺	% α =100

α radiations

E α	E(level)	I α [‡]	HF [†]	Comments
6602 4	0.0	100	1.0	E α : weighted average of 6611 30 (1989Ho12), 6619 10 (1996Bi07), and 6600 3 (2000Ma95). I α : only one α branch is reported.

[†] r₀(¹⁵⁸W)=1.5597 29 is calculated from HF(6602 α)=1.0.

[‡] Absolute intensity per 100 decays.